BESPM VIII EXICCOLD) AME

17/12/15-

QP Code : 2640

(3 Hours)

[Total Marks : 100

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- N.B.: (1) Question No.1 is compulsory.
 - Solve any four questions out of remaining six questions. (2)
 - (3) Use of smith chart is allowed.
 - Figures to the right indicate full marks. (4)
- What is an unilateral figure of merit of an amplifier? 1. (a)
 - (b) Define signal to noise ratio and noise figure with help of a noisy network.
- (d) Explain the terms conversion loss and isolation with reference to mixer. S
 (a) For an ideal transformer with turns and isolation with reference to mixer. S For an ideal transformer with turns ratio $n = \frac{m}{n_2}$. Prove that the scattering matrix 2. (a) 10 is : SPEDA

$$S = \begin{bmatrix} \frac{n^2 - 1}{n^2 + 1} & \frac{2n}{n^2 + 1} \\ \frac{2n}{n^2 + 1} & \frac{1 - n^2}{n^2 + 1} \end{bmatrix}$$

- (b) Discuss amplifier linearization methods.
- A GaAs FET has the following S-parameter and noise parameters at 1.0 GHz 20 $(Z_0 = 50 \ \Omega) \ S_{11} = 0.61 < -155^{\circ}, \ S_{12} = 0.51 < -20^{\circ}, \ S_{21} = 5.0 < 180^{\circ}, \ S_{22} = 0.51 < -20^{\circ},$ $F_{min} = 3dB$, $\Gamma_{opt} = 0.45 < 180^{\circ}$, $R_N = 40^{\circ}$. Design a Low noise amplifier for a noise figure of 3.5dB and power gain of 16 dB.
- Derive the transducer power gain as **4**. (a)

$$G_{T} = \frac{P_{L}}{P_{svg}} = \frac{|S_{2l}|^{2} (1 - |\Gamma_{s}|^{2}) (1 - |\Gamma_{L}|^{2})}{(1 - \Gamma_{s}\Gamma_{in}|^{2} |1 - S_{22}\Gamma_{L}|^{2}}$$

(b) Design a transistor scillator at 4 GHz using GaAs FET in common gate configuration 10 with 5nH inductor in series. Common gate configuration S-parameters are $S_{11} = 2.18 < -35^{\circ}$, $S_{21} = 2.75 < 96^{\circ}$, $S_{12} = 1.26 < 18^{\circ}$, $S_{22} = 0.52 < 155^{\circ}$, 10 Select $\Gamma_{in} > 1$.

TURN OVER

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- Explain using suitable diagrams two methods of designing broadband amplifier. 5.(a) (b) Discuss generator tuning networks for microwave oscillators.
- Explain in detail single ended diode mixer. Also explain mixer design aspects. 6. (a)
- 10 10 0 10 0 10 10 10 (b) A BJT with $I_c = 30$ mA and $V_{cc} = 10$ V is operated at a frequency of 1.0 GHz in 4×10 50 Ω system. $S_{11} = 0.73 < 175^{\circ}, S_{22} = 0.21 < -89^{\circ}, S_{12} = 0.0, S_{21} = 4.45 < 65^{\circ}$ $S_{11} = 0.75 \le 175$, $S_{22} = 0.21 \le -65^{\circ}$, $S_{12} = 0.0$, $S_{21} = 4.45 \le 65^{\circ}$ Is the transistor unconditionally stable? If yes, calculate the optimum terminations. G_{Smax} , G_{Lmax} and G_{TUmax} . Write short note on : (a) Noise figure test equipment (b) Comparison of microwave amplifier and oscillator (c) 1dB compression point
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Dec 2015

BE-SEM JIII CR-WOT) - EXTL Mixeley Netwohr

QP Code : 2991

(3 Hours)

[Total Marks: 100

	N. B .	 (1) Question No. 1 is compulsory (2) Attempt any four out of remaining q.no. 2 to 7 (3) Draw neat Sketches wherever required 	13
		(4) Assume suitable data if required.	See.
) ·
	1. (a)) Why is power control is important in CDMA?	5
	(b)) What is the difference between an ESS and a BSS in the IEEE 802.11?	5
	(C)) Discuss two evolution paths for the GSM to offer 3G Services.	5
	(a)	what is HSDPA?	5
	2 (2)	Differentiate between frequency have increased in	
	2. (u)	What are various states in Bluetooth Sustana Franks, diego with the	5 5 5 5 5 5 10 10 10 10 10 10 10 10 10 10 10 10 10
	(0)	and the various states in Bluetoon system? Explain difference between them.	10
	3. (a)	What is a WPAN? What is the difference between WPAN and WI ANI2 Name have	10
		example technologies for WPAN.	10
	(ይ)	What is WAP? Discuss WAP architecture in brief.	10
		-35	10
	4. (a)	What is the UMTS? List important features of the UMTS air interface.	'10 -
-	(b)	Discuss forward and reverse link channels in the cdma 2000	10
	5 (0)	Exploin Divete eth anote ethant	
	J. (a)	Explain Sensor petwork protocol stack	10
		Explain sensor herwork protocol stack in detail.	10
	6. (a)	Explain link budget analysis and requirements of wireless networks	
	(b)	Discuss WiMAX. What are the main differences between the IEEE 802 116 (WG E:)	10
		and WIMAX?	10
		4.	
	7. Wr	ite short notes on S	
		(a) IEEE Project 802	10
		(b) RFID	10
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B.E. Sem VIII (R-2007) (BXTC). 16/12/15 IP

(REVISED COURSE)

QP Code : 2721

(3 Hours)

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[Total Marks: 100

	. Answer any 4 questions from the remaining questions	
Q1	Write short notes on any four	20
	a. Connectivity of pixels	(``
	b. Median filters	1
	c. Slant transform	5
	d. Edge detection	
	e. Inresholding and its application.	
Q2	a. Explain Image formation in eye with neat diagram.	10
	b. Explain the following filtering operations in spatial domain.	10
	1. Low pass filtering ii. High pass filtering iii. High Boost filtering	
Q3	a. Perform histogram Equalization for the following image. Plot the original and the	10
	Equalized Histograms.	10
	Intensity 0 1 2 3 4 5 6 7	
	No.of pixels 130 100 40 60 40 80 10 40	
	b. while heat block diagram, explain the basics of filtering in the frequency domain.	107
Q4	a. Explain the method of segmentation of images by region splitting and region growing.	10
	Find out Huffman code words and efficiency and a surface surfa	10
	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	10
Qo	a. Derive a mathematical model for image degradation function.	10
		10
Q7	Write short notes on any two	20
	a. Hotelling Transform	
	b. Homorrorphic Filters	
	u. riuggi transform d. Infare compression standards	
	u marge compression standards	
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